



勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
 Http://www.100y.com.tw

DualCool™ N-Channel NexFET™ Power MOSFET

 Check for Samples: **CSD16407Q5C**

FEATURES

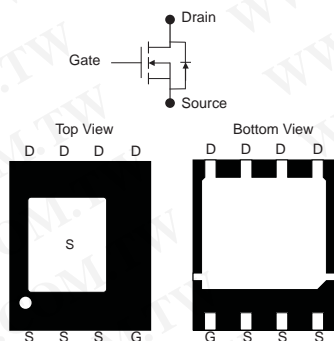
- Ultralow Q_g and Q_{gd}
- DualCool™ Package
- Optimized for Two Sided Cooling
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm x 6-mm Plastic Package

APPLICATIONS

- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems
- Optimized for Synchronous FET Applications

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.



PRODUCT SUMMARY

V_{DS}	Drain to Source Voltage	25	V
Q_g	Gate Charge Total (4.5V)	13.3	nC
Q_{gd}	Gate Charge Gate to Drain	3.5	nC
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 4.5V$	2.5 mΩ
		$V_{GS} = 10V$	1.8 mΩ
$V_{(th)}$	Threshold Voltage	1.6	V

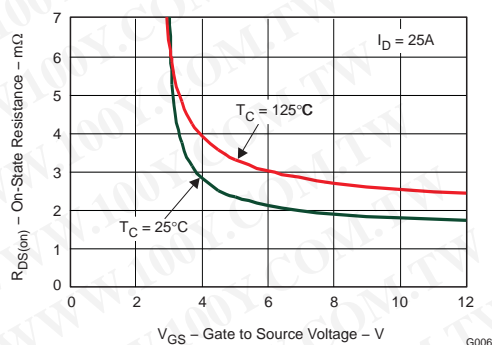
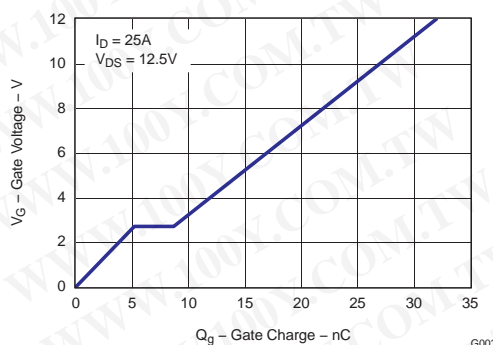
ORDERING INFORMATION

Device	Package	Media	Qty	Ship
CSD16407Q5C	SON 5-mm x 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ C$ unless otherwise stated		VALUE	UNIT
V_{DS}	Drain to Source Voltage	25	V
V_{GS}	Gate to Source Voltage	+16 / -12	V
I_D	Continuous Drain Current, $T_C = 25^\circ C$	100	A
	Continuous Drain Current ⁽¹⁾	31	A
I_{DM}	Pulsed Drain Current, $T_A = 25^\circ C$ ⁽²⁾	200	A
P_D	Power Dissipation ⁽¹⁾	3.1	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ C$
E_{AS}	Avalanche Energy, single pulse $I_D = 66A, L = 0.1mH, R_G = 25\Omega$	218	mJ

- (1) Typical $R_{\theta JA} = 40^\circ C/W$ on 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.
- (2) Pulse duration $\leq 300\mu s$, duty cycle $\leq 2\%$

 $R_{DS(on)}$ vs V_{GS}

GATE CHARGE


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

DualCool, NexFET are trademarks of Texas Instruments.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$, unless otherwise specified

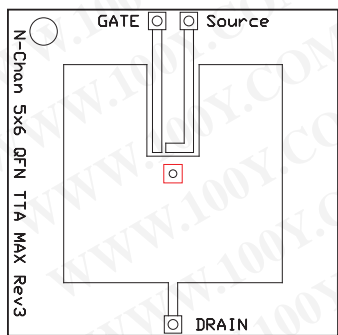
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
BV_{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	25			V
I_{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 20V$			1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +16V / -12V$			100	nA
$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.3	1.6	1.9	V
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 25A$		2.5	3.3	m Ω
		$V_{GS} = 10V, I_D = 25A$		1.8	2.4	m Ω
g_{fs}	Transconductance	$V_{DS} = 15V, I_D = 25A$		111		S
Dynamic Characteristics						
C_{ISS}	Input Capacitance	$V_{GS} = 0V, V_{DS} = 12.5V, f = 1MHz$		2040	2660	pF
C_{OSS}	Output Capacitance			1600	2080	pF
C_{RSS}	Reverse Transfer Capacitance			115	160	pF
R_g	Series Gate Resistance			1.2	2.4	Ω
Q_g	Gate Charge Total (4.5V)	$V_{DS} = 12.5V, I_D = 25A$		13.3	18	nC
Q_{gd}	Gate Charge Gate to Drain			3.5		nC
Q_{gs}	Gate Charge Gate to Source			5.3		nC
$Q_{g(th)}$	Gate Charge at V_{th}			3.1		nC
Q_{OSS}	Output Charge	$V_{DS} = 13.5V, V_{GS} = 0V$		33		nC
$t_{d(on)}$	Turn On Delay Time	$V_{DS} = 12.5V, V_{GS} = 4.5V, I_D = 25A, R_G = 2\Omega$		11.9		ns
t_r	Rise Time			18.4		ns
$t_{d(off)}$	Turn Off Delay Time			16		ns
t_f	Fall Time			9		ns
Diode Characteristics						
V_{SD}	Diode Forward Voltage	$I_S = 25A, V_{GS} = 0V$		0.8	1	V
Q_{rr}	Reverse Recovery Charge	$V_{DD} = 13.5V, I_F = 25A, di/dt = 300A/\mu s$		42		nC
t_{rr}	Reverse Recovery Time	$V_{DD} = 13.5V, I_F = 25A, di/dt = 300A/\mu s$		34		ns

THERMAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$, unless otherwise specified

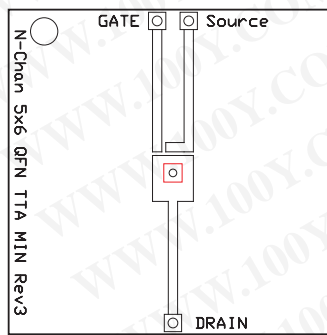
PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case (Top Source) ⁽¹⁾			1.2	$^\circ\text{C/W}$
$R_{\theta JC}$	Thermal Resistance Junction to Case (Bottom Drain) ⁽¹⁾			1.1	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient ^{(1) (2)}			51	$^\circ\text{C/W}$

- (1) $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design.
- (2) Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.



Max $R_{\theta JA} = 51^{\circ}\text{C/W}$
 when mounted on
 1 inch² (6.45 cm²) of
 2-oz. (0.071-mm thick)
 Cu.

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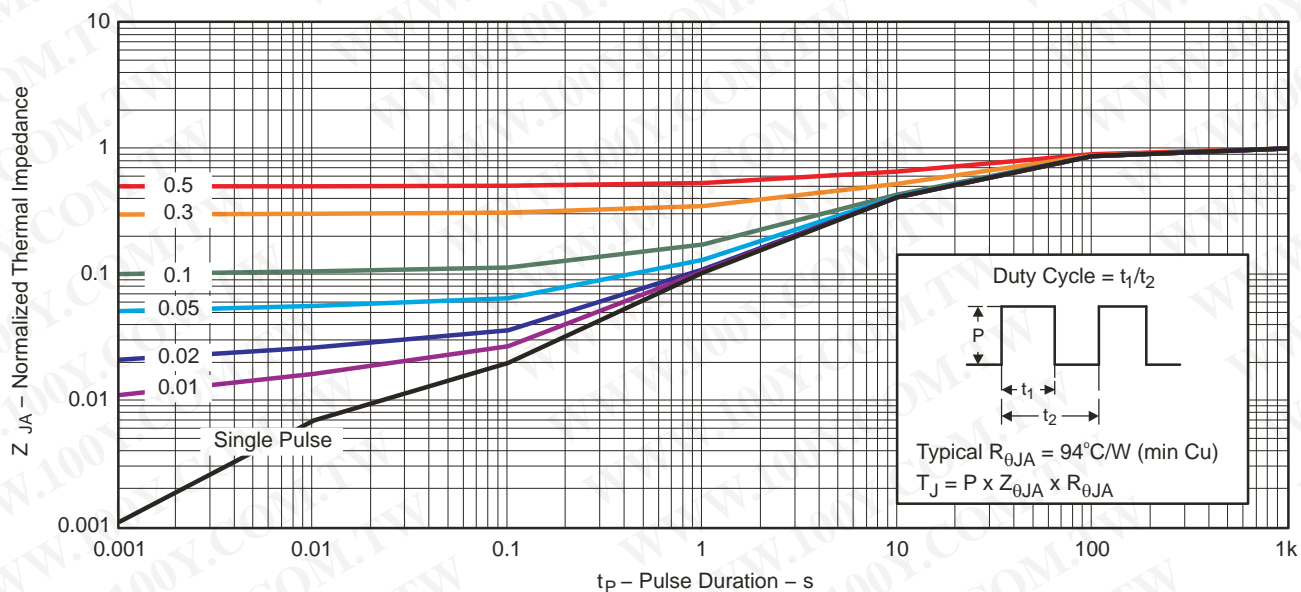
Max $R_{\theta JA} = 121^{\circ}\text{C/W}$
 when mounted on
 minimum pad area of
 2-oz. (0.071-mm thick)
 Cu.

M0137-02

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TYPICAL MOSFET CHARACTERISTICS

$T_A = 25^{\circ}\text{C}$, unless otherwise specified



G012

Figure 1. Transient Thermal Impedance

TYPICAL MOSFET CHARACTERISTICS (continued)

T_A = 25°C, unless otherwise specified

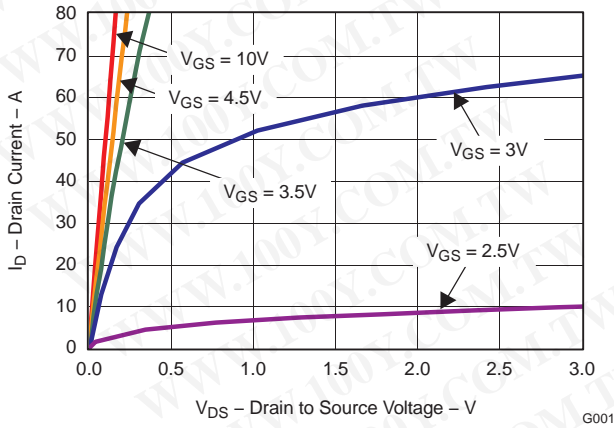


Figure 2. Saturation Characteristics

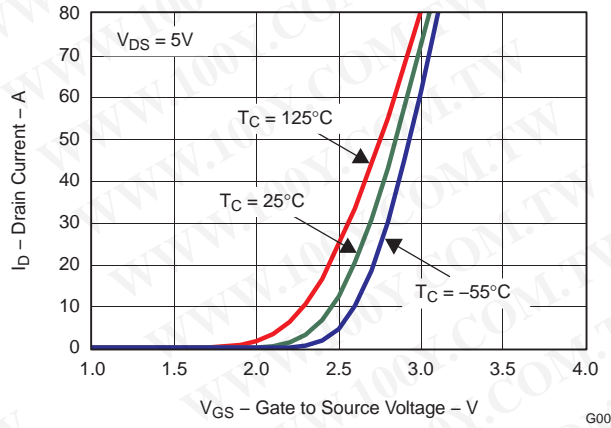


Figure 3. Transfer Characteristics

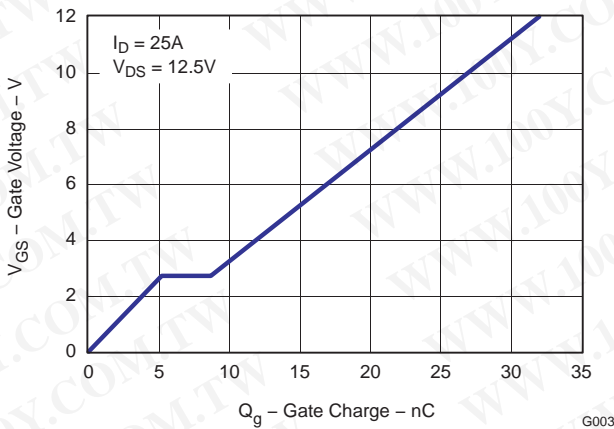


Figure 4. Gate Charge

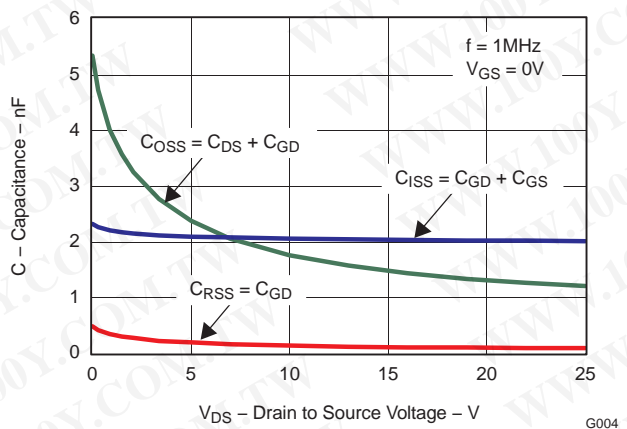


Figure 5. Capacitance

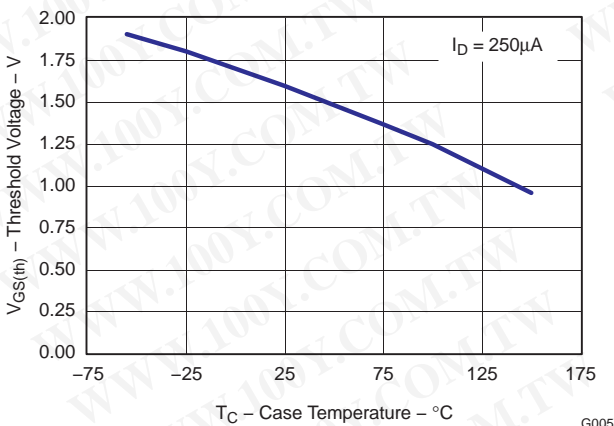


Figure 6. Threshold Voltage vs. Temperature

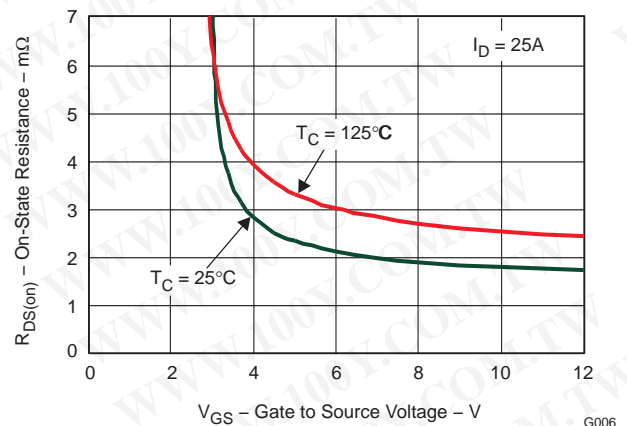


Figure 7. On-State Resistance vs. Gate to Source Voltage

TYPICAL MOSFET CHARACTERISTICS (continued)

T_A = 25°C, unless otherwise specified

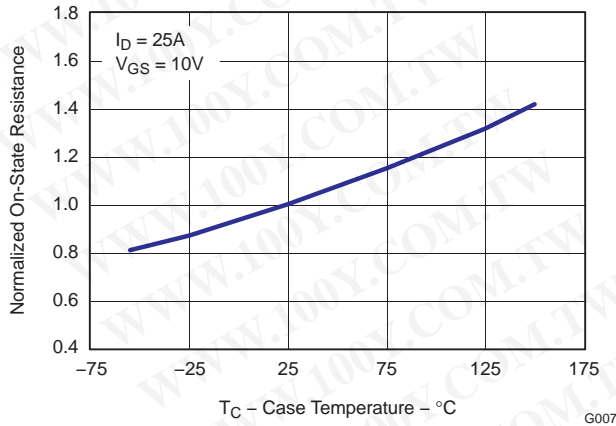


Figure 8. Normalized On-State Resistance vs. Temperature

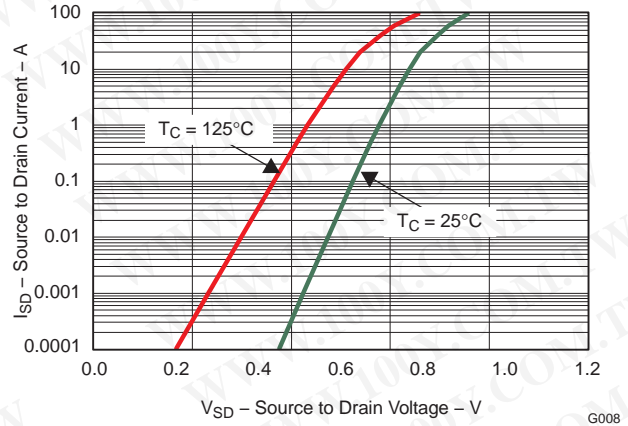


Figure 9. Typical Diode Forward Voltage

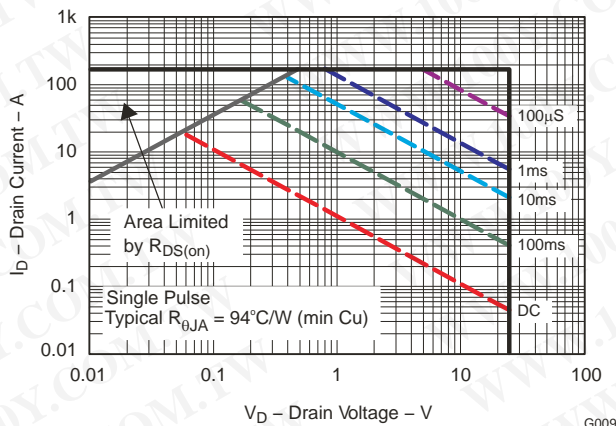


Figure 10. Maximum Safe Operating Area

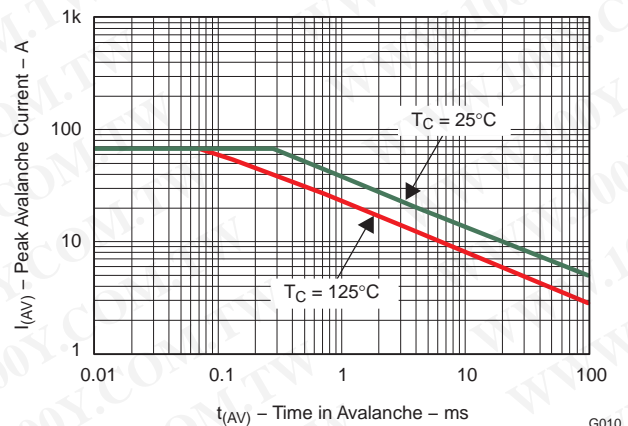


Figure 11. Single Pulse Unclamped Inductive Switching

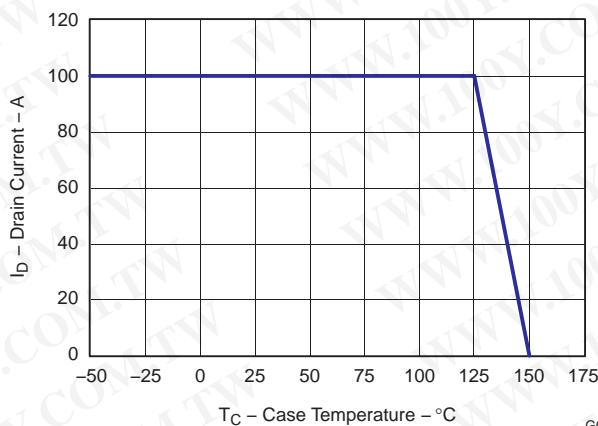
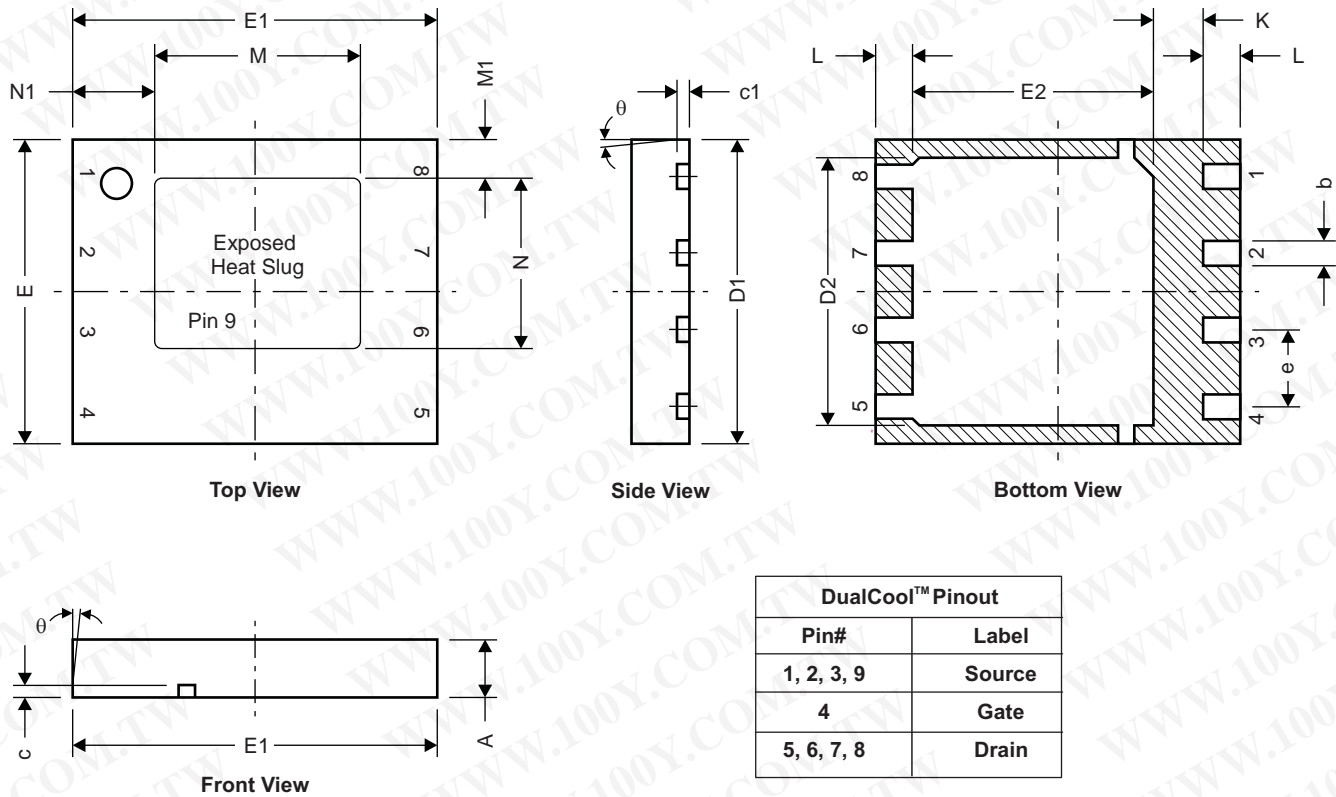


Figure 12. Maximum Drain Current vs. Temperature

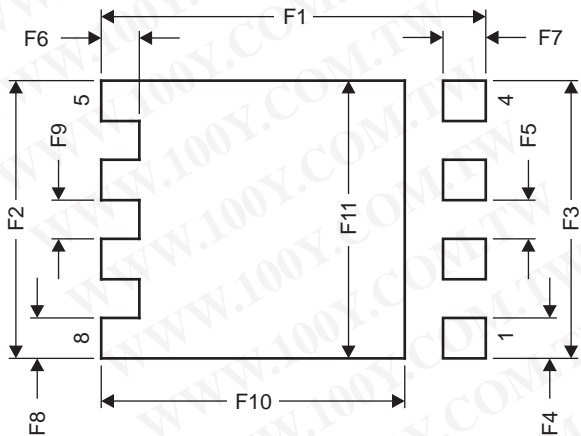
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MECHANICAL DATA**Q5C Package Dimensions**

M0162-01

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.950	1.050	0.037	0.039
b	0.360	0.460	0.014	0.018
c	0.150	0.250	0.006	0.010
c1	0.150	0.250	0.006	0.010
D1	4.900	5.100	0.193	0.201
D2	4.320	4.520	0.170	0.178
E	4.900	5.100	0.193	0.201
E1	5.900	6.100	0.232	0.240
E2	3.920	4.12	0.154	0.162
e	1.27 TYP		0.050	
K	0.760	–	0.030	–
L	0.510	0.710	0.020	0.028
θ	–	–	–	–
M	3.260	3.460	0.128	0.136
M1	0.520	0.720	0.020	0.028
N	2.720	2.920	0.107	0.115
N1	1.227	1.427	0.048	0.056

Recommended PCB Pattern

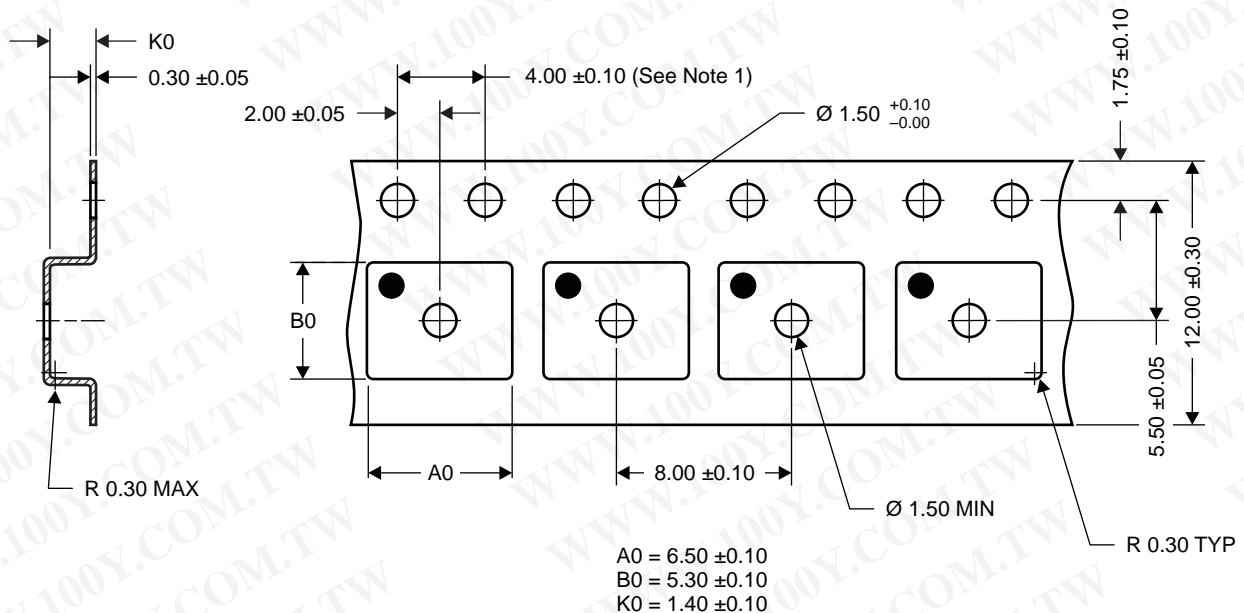


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DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.460	4.560	0.176	0.180
F3	4.460	4.560	0.176	0.180
F4	0.650	0.700	0.026	0.028
F5	0.620	0.670	0.024	0.026
F6	0.630	0.680	0.025	0.027
F7	0.700	0.800	0.028	0.031
F8	0.650	0.700	0.026	0.028
F9	0.620	0.670	0.024	0.026
F10	4.900	5.000	0.193	0.197
F11	4.460	4.560	0.176	0.180

For recommended circuit layout for PCB designs, see application note [SLPA005 – Reducing Ringing Through PCB Layout Techniques](#).

Q5C Tape and Reel Information



M0138-01

Notes:

1. 10-sprocket hole-pitch cumulative tolerance ± 0.2
2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
3. Material: black static-dissipative polystyrene
4. All dimensions are in mm, unless otherwise specified.
5. Thickness: 0.30 ± 0.05 mm
6. MSL1 260°C (IR and convection) PbF reflow compatible

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Package Marking Information

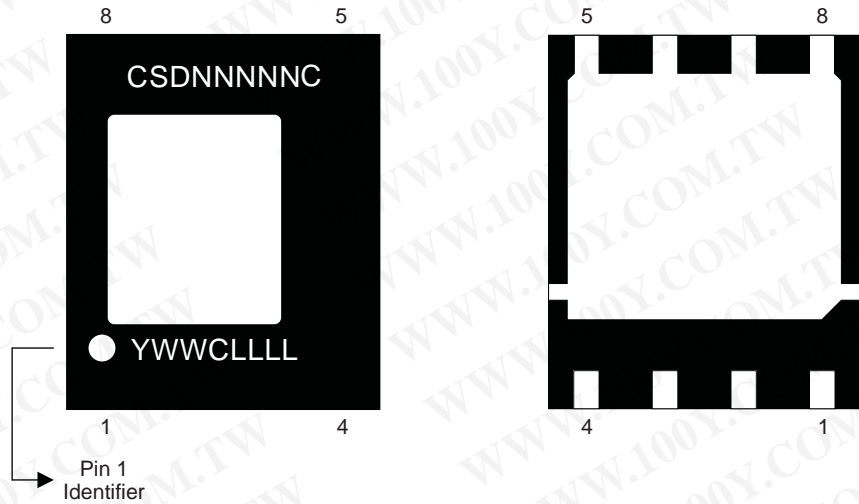
Location

1st Line

- CSD = Fixed Characters
- NNNNN = 5-digit Product Code
- C = DualCool Package

2nd Line (Date Code)

- Y = Last digit of the Year
- WW = 2-digit Work Week
- C = Country of Origin
 - > Philippines = P
 - > Taiwan = T
 - > China = C
- LLLL = Last 4 digits of the Wafer Lot #



M0163-01

REVISION HISTORY

Changes from Original (October 2009) to Revision A	Page
• Changed the device From: Procut Preview To: Production	1
• Changed Application - From: Optimized for Control FET Applications To: Optimized for Synchronous FET Applications	1
• Changed the pinout illustration.	1
• Changed the Q5C Package Dimensions illustration	6
Changes from Revision A (December 2009) to Revision B	Page
• Changed the ABSOLUTE MAXIMUM RATINGS table, I _D - Continuous Drain Current value From: 30A To: 31A	1
• Changed Note 1 of the ABSOLUTE MAXIMUM RATINGS table From: Typical R _{θJA} = 41°C To: Typical R _{θJA} = 40°C	1
• Changed Figure 1 - From: Typical R _{θJA} = 98°C/W To: Typical R _{θJA} = 94°C/W	3
• Changed Figure 10 - From: Typical R _{θJA} = 98°C/W To: Typical R _{θJA} = 94°C/W	5
• Changed Figure 11 - X axis values	5
Changes from Revision B (January 2010) to Revision C	Page
• Changed the labels on the Bottom View pinout image	1

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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CSD16407Q5C	ACTIVE	SON	DQU	8	2500	Pb-Free (RoHS Exempt)	Call TI	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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